

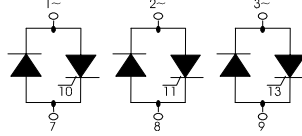
Three Phase AC Controller Modules

PSUH 36

I_{RMS} = 3 x 39A
 V_{RRM} = 400-1600 V

V_{RSM} V_{DSM}	V_{RRM} V_{DRM}	Type
500	400	PSUH 36/04
900	800	PSUH 36/08
1300	1200	PSUH 36/12
1500	1400	PSUH 36/14
*1700	*1600	PSUH 36/16

* Delivery on request



Symbol	Test Conditions	Maximum Ratings
I_{RMS}	$T_C = 85^\circ C$, 50-400 Hz (per phase)	39 A
I_{TRMS}	$T_{VJ} = T_{VJM}$	28 A
I_{TAVM}	$T_C = 85^\circ C$ 180° sine	18 A
I_{TSM}	$T_{VJ} = 45^\circ C$ t = 10 ms (50 Hz), sine	320 A
	$V_R = 0$ t = 8.3 ms (60 Hz), sine	350 A
	$T_{VJ} = T_{VJM}$ t = 10 ms (50 Hz), sine	280 A
	$V_R = 0$ t = 8.3 ms (60 Hz), sine	310 A
$\int i^2 dt$	$T_{VJ} = 45^\circ C$ t = 10 ms (50 Hz), sine	500 A ² s
	$V_R = 0$ t = 8.3 ms (60 Hz), sine	520 A ² s
	$T_{VJ} = T_{VJM}$ t = 10 ms (50 Hz), sine	390 A ² s
	$V_R = 0$ t = 8.3 ms (60 Hz), sine	400 A ² s
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ repetitive, $I_T = 20$ A	150 A/ μ s
	f = 50Hz, $t_p = 200\mu$ s	
	$V_D = 2/3 V_{DRM}$	
	$I_G = 0.3$ A non repetitive, $I_T = I_{TAVM}$	500 A/ μ s
$(dv/dt)_{cr}$	$T_{VJ} = T_{VJM}$ $V_{DR} = 2/3 V_{DRM}$	1000 V/ μ s
	$R_{GK} = \infty$, method 1 (linear voltage rise)	
P_{GM}	$T_{VJ} = T_{VJM}$ $t_p = 30\mu$ s	10 W
	$I_T = I_{TAVM}$ $t_p = 300\mu$ s	5 W
P_{GAVM}		0.5 W
V_{RGM}		10 V
T_{VJ}		-40 ... + 125 °C
T_{VJM}		125 °C
T_{stg}		-40 ... + 125 °C
V_{ISOL}	50/60 HZ, RMS t = 1 min	2500 V ~
	$I_{ISOL} \leq 1$ mA t = 1 s	3000 V ~
M_d	Mounting torque (M5)	2-2.5 Nm
Weight	typ.	100 g

Features

- Thyristor controller for AC (circuit W3C acc. to IEC) for mains frequency
- Isolation voltage 3000 V~
- Planar glasspassivated chips
- Package with metal base plate
- UL registered E 148688

Applications

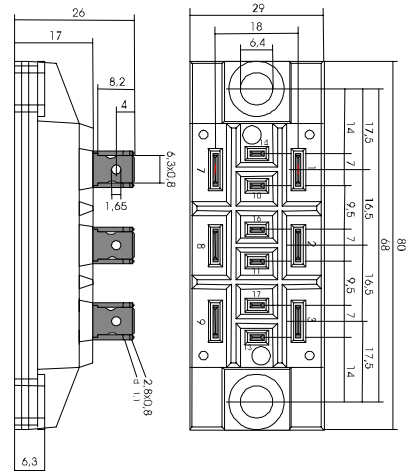
- Switching and control of three phase AC circuits
- Light and temperature control
- Softstart AC motor controller
- Solid state switches

Advantages

- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- High power density

Package, stil and outline

Dimensions in mm (1mm = 0.0394")



Symbol	Test Conditions	Characteristic Value	
I_D, I_R	$T_{VJ} = T_{VJM}, V_R = V_{RRM}, V_D = V_{DRM}$	≤ 5 mA	
V_T	$I_T = 45A, T_{VJ} = 25^\circ C$	≤ 1.45 V	
V_{TO}	For power-loss calculations only ($T_{VJ} = T_{VJM}$)	0.85 V	
r_T		13 m Ω	
V_{GT}	$V_D = 6V$	$T_{VJ} = 25^\circ C$	≤ 1.0 V
		$T_{VJ} = -40^\circ C$	≤ 1.2 V
I_{GT}	$V_D = 6V$	$T_{VJ} = 25^\circ C$	≤ 65 mA
		$T_{VJ} = -40^\circ C$	≤ 80 mA
V_{GD}	$T_{VJ} = T_{VJM}, V_D = 2/3 V_{DRM}$	≤ 0.2 V	
I_{GD}	$T_{VJ} = T_{VJM}, V_D = 2/3 V_{DRM}$	≤ 5 mA	
I_L	$T_{VJ} = 25^\circ C, t_p = 10\mu s$	≤ 150 mA	
	$I_G = 0.3A, di_G/dt = 0.3A/\mu s$		
I_H	$T_{VJ} = 25^\circ C, V_D = 6V, R_{GK} = \infty$	≤ 100 mA	
t_{gd}	$T_{VJ} = 25^\circ C, V_D = 1/2 V_{DRM}$	≤ 2 μs	
	$I_G = 0.3A, di_G/dt = 0.3A/\mu s$		
t_q	$T_{VJ} = T_{VJM}, I_T = 20A, t_p = 200\mu s, V_R = 100V$	150 μs	
	$-di/dt = 10A/\mu s, dv/dt = 15V/\mu s, V_D = 2/3 V_{DRM}$		
R_{thJC}	per thyristor; sine 180°el	1.3 K/W	
	per module	0.22 K/W	
R_{thJK}	per thyristor; sine 180° el	1.5 K/W	
	per module	0.25 K/W	
d_s	Creeping distance on surface	16.1 mm	
d_A	Creeping distance in air	6.0 mm	
a	Max. allowable acceleration	50 m/s ²	